

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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### DHG20C600PB

preliminary

600 V  $V_{RRM}$ 

I<sub>FAV</sub> 10 A

35 ns

High Performance Fast Recovery Diode Low Loss and Soft Recovery Common Cathode

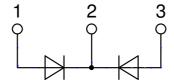
**Sonic Fast Recovery Diode** 

Part number

#### DHG20C600PB



Backside: cathode



#### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low Irm reduces:
- Power dissipation within the diode
- Turn-on loss in the commutating switch

#### **Applications:**

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: TO-220

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

#### Terms \_Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office.

Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office.

Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

to perform joint risk and quality assessments;
the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

IXYS reserves the right to change limits, conditions and dimensions.

Data according to IEC 60747 and per semiconductor unless otherwise specified

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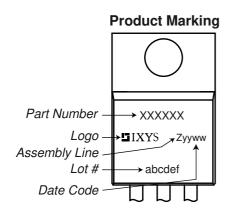
Fast Diode				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V <sub>RSM</sub>	max. non-repetitive reverse blocki	ing voltage	$T_{VJ} = 25^{\circ}C$			600	V
V <sub>RRM</sub>	max. repetitive reverse blocking v	oltage	$T_{VJ} = 25^{\circ}C$			600	V
I <sub>R</sub>	reverse current, drain current	V <sub>R</sub> = 600 V	$T_{VJ} = 25^{\circ}C$			30	μΑ
		$V_R = 600 \text{ V}$	$T_{VJ} = 125^{\circ}C$			1.2	mΑ
V <sub>F</sub>	forward voltage drop	I <sub>F</sub> = 10 A	$T_{VJ} = 25^{\circ}C$			2.23	٧
		$I_F = 20 A$				3.13	٧
		I <sub>F</sub> = 10 A	T <sub>vJ</sub> = 125°C			2.18	V
		$I_F = 20 A$				3.29	٧
I <sub>FAV</sub>	average forward current	$T_c = 95^{\circ}C$	T <sub>VJ</sub> = 150°C			10	Α
		rectangular $d = 0.5$					! ! !
V <sub>F0</sub>	threshold voltage		T <sub>vJ</sub> = 150°C			1.04	V
r <sub>F</sub>	slope resistance } for power lo	oss calculation only				104	mΩ
R <sub>thJC</sub>	thermal resistance junction to cas	e				1.8	K/W
R <sub>thCH</sub>	thermal resistance case to heatsing	nk			0.50		K/W
P <sub>tot</sub>	total power dissipation		$T_C = 25^{\circ}C$			70	W
I <sub>FSM</sub>	max. forward surge current	$t = 10 \text{ ms}$ ; (50 Hz), sine; $V_R = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$			80	Α
CJ	junction capacitance	$V_R = 400 V$ f = 1 MHz	$T_{VJ} = 25^{\circ}C$		6		pF
I <sub>RM</sub>	max. reverse recovery current	<u> </u>	T <sub>VJ</sub> = 25 °C		4		Α
		$I_F = 10 \text{ A}; V_R = 400 \text{ V}$	$T_{VJ} = {}^{\circ}C$		tbd		Α
t <sub>rr</sub>	reverse recovery time	$\begin{cases} I_F = 10 \text{ A; } V_R = 400 \text{ V} \\ -di_F /dt = 200 \text{ A/}\mu\text{s} \end{cases}$	$T_{VJ} = 25 ^{\circ}\text{C}$		35		ns
=*		)	$T_{VJ} = {}^{\circ}C$		tbd		ns



## DHG20C600PB

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Package TO-220			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I <sub>RMS</sub>	RMS current	per terminal 1)			35	Α
T <sub>VJ</sub>	virtual junction temperature		-55		150	°C
Top	operation temperature		-55		125	°C
T <sub>stg</sub>	storage temperature		-55		150	°C
Weight				2		g
M <sub>D</sub>	mounting torque		0.4		0.6	Nm
<b>F</b> <sub>c</sub>	mounting force with clip		20		60	Ν



#### Part description

D = Diode

H = Sonic Fast Recovery Diode

G = extreme fast

20 = Current Rating [A]

C = Common Cathode 600 = Reverse Voltage [V] PB = TO-220AB (3)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DHG20C600PB	DHG20C600PB	Tube	50	505287

Similar Part	Package	Voltage class
DHG20C600QB	TO-3P (3)	600

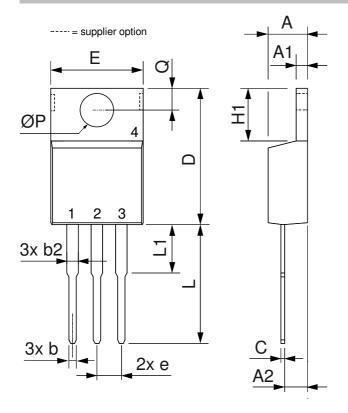
<b>Equivalent Circuits for Simulation</b>			* on die level	T <sub>vJ</sub> = 150 °C
$I \rightarrow V_0$	)— <u>R</u> o	Fast Diode		
V <sub>0 max</sub>	threshold voltage	1.04		V
R <sub>0 max</sub>	slope resistance *	101		$m\Omega$





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### Outlines TO-220



Dim.	Millimeter		Inches		
	Min.	Max.	Min.	Max.	
Α	4.32	4.82	0.170	0.190	
A1	1.14	1.39	0.045	0.055	
A2	2.29	2.79	0.090	0.110	
b	0.64	1.01	0.025	0.040	
b2	1.15	1.65	0.045	0.065	
С	0.35	0.56	0.014	0.022	
D	14.73	16.00	0.580	0.630	
Е	9.91	10.66	0.390	0.420	
е	2.54	BSC	0.100	BSC	
H1	5.85	6.85	0.230	0.270	
L	12.70	13.97	0.500	0.550	
L1	2.79	5.84	0.110	0.230	
ØP	3.54	4.08	0.139	0.161	
Q	2.54	3.18	0.100	0.125	

